

# 150mA, 75V Switching Diode

#### **FEATURES**

- Low power loss, high efficiency
- Ideal for automated placement
- High surge current capability
- Moisture sensitivity level: level 1, per J-STD-020
- Compliance to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

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- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- On-board DC/DC converter

#### **MECHANICAL DATA**

- Case: 1206(Ceramics)
- Molding compound meets UL flammability classification rating 94HB
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Polarity: Indicated by cathode band
- Weight: 0.01g (approximately)

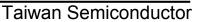
KEY PARAMETERS					
PARAMETER	VALUE	UNIT			
P <sub>D</sub>	500	mW			
I <sub>F(AV)</sub>	150	mA			
$V_{RRM}$	75	V			
I <sub>FSM</sub>	2	Α			
V <sub>F</sub> at I <sub>F</sub> =100mA	1.00	V			
T <sub>J</sub> Max.	150	°C			
Package	1206 (Ceramics)				
Configuration	Single die				







ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Power dissipation		$P_{D}$	500	mW		
Repetitive peak reverse voltage	V <sub>RRM</sub> 75		V			
Non-repetitive peak reverse voltage	$V_{RSM}$	100	V			
Forward current	I <sub>F(AV)</sub>	150	mA			
Repetitive peak forward current	I <sub>FRM</sub>	300	mA			
Non-repetitive peak forward surge	tp = 1s square wave		0.5			
current	tp = 8.3ms single half sine wave	I <sub>FSM</sub>	2.0	- A		
Junction temperature range	$T_J$	-55 to +150	°C			
Storage temperature range	T <sub>STG</sub>	-55 to +150	°C			





THERMAL PERFORMANCE						
PARAMETER	SYMBOL	TYP.	UNIT			
Junction-to-ambient thermal resistance	$R_{\Theta JA}$	375	°C/W			

ELECTRICAL SPECIFICATIONS (T <sub>A</sub> = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	TYP.	MAX.	UNIT	
Reverse breakdown voltage (2)	I <sub>R</sub> =100μA, T <sub>J</sub> =25°C	V <sub>R</sub>	75	-	V	
Forward voltage per diode (1)	I <sub>F</sub> =100mA, T <sub>J</sub> =25°C	V <sub>F</sub>	-	1	V	
Reverse recovery time	$I_F=10\text{mA}, I_R=10\text{mA},$ $R_L=100\Omega$	t <sub>rr</sub>	-	4	ns	
Reverse current @ rated V <sub>R</sub> per	V <sub>R</sub> =20V T <sub>J</sub> =25°C		-	25	nA	
diode (2)	V <sub>R</sub> =75V T <sub>J</sub> =25°C	I <sub>R</sub>	-	5	μΑ	
Junction capacitance	1 MHz, V <sub>R</sub> =0V	Сл	-	4	pF	

### Notes:

- 1. Pulse test with PW=0.3 ms
- 2. Pulse test with PW=30 ms

ORDERING INFORMATION						
ORDERING CODE	PACKAGE	PACKING				
TS4148 RXG	1206	5K / 7" Reel				
TS4148 RAG	1200	10K / 13" Reel				



#### **CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25°C unless otherwise noted)

Fig. 1 Typical Forward Characteristics 1000 Instantaneous Forward Current (mA) 100 10 T<sub>A</sub>=100°C T<sub>A</sub>=25°C 0.1 0.01 0.2 0.0 0.4 0.6 8.0 1.0 1.6 Instantaneous Forward Voltage (V)

Fig. 2 Reverse Current VS. Reverse Voltage

100.00

T<sub>A</sub>=25°C

0.10

0 20 40 60 80 100 120

Reverse Voltage (V)

Fig. 3 Admissible Power Dissipation Curve

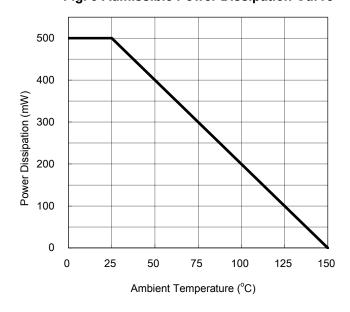
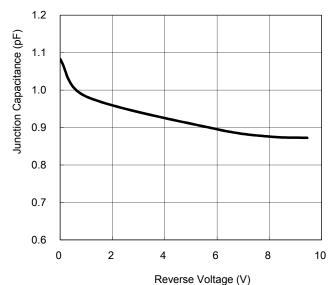


Fig. 4 Typical Junction Capacitance

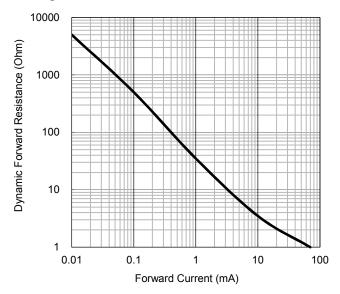




### **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

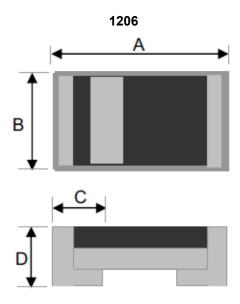
Fig. 5 Forward Resistance VS. Forward Current







## **PACKAGE OUTLINE DIMENSION**



DIM	Unit (	mm)	Unit (inch)		
DIM.	Min	Max	Min	Max	
Α	3.00	3.40	0.118	0.134	
В	1.30	1.70	0.051	0.067	
С	0.35	0.75	0.014	0.030	
D	0.65	0.85	0.026	0.033	

Version:O1803

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